



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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IR Emitter and Detector Product Data Sheet

LTR-546AB

Spec No.: DS-50-98-0010

Effective Date: 05/18/2010

Revision: B

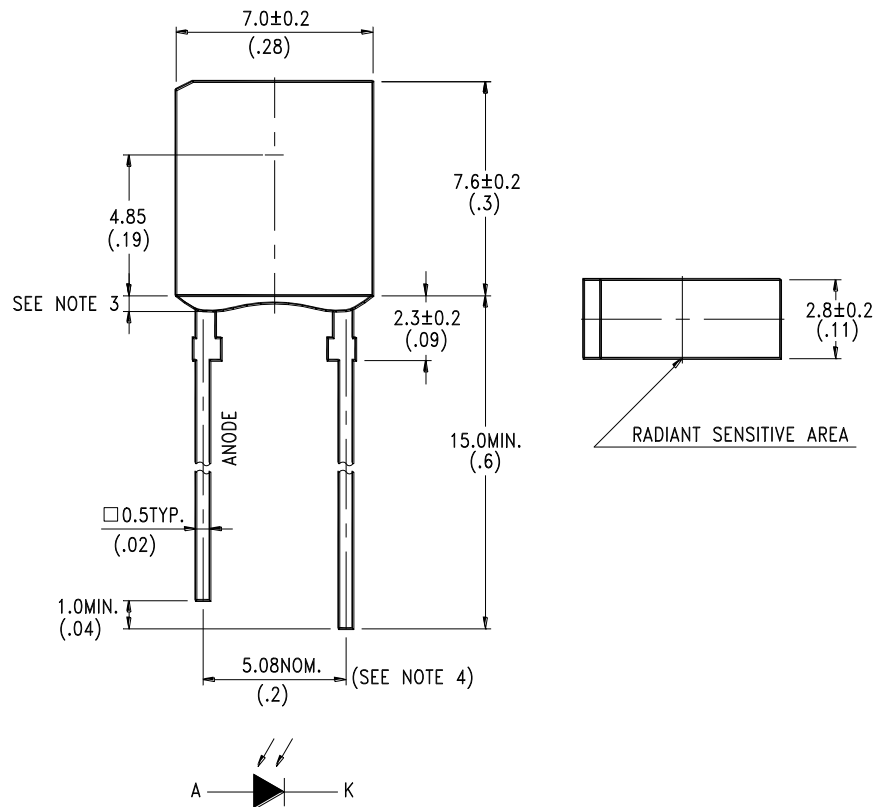
LITE-ON DCC

RELEASE

BNS-OD-FC001/A4

FEATURES

- * HIGH PHOTO SENSITIVITY
- * SUITABLE FOR INFRARED RADIATION
- * LOW JUNCTION CAPACITANCE
- * HIGH CUT-OFF FREQUENCY
- * FAST SWITCHING TIME
- * THE LTR-546AB IS A SPECIAL DARK BLUE PLASTIC PACKAGE THAT CUT THE VISIBLE LIGHT AND SUITABLE FOR THE DETECTORS OF INFRARED APPLICATIONS

PACKAGE DIMENSIONS**NOTES:**

1. All dimensions are in millimeters (inches).
2. Tolerance is ± 0.25 mm(.010") unless otherwise noted.
3. Protruded resin under flange is 1.5mm(.059") max.
4. Lead spacing is measured where the leads emerge from the package.
5. Specifications are subject to change without notice.



LITE-ON TECHNOLOGY CORPORATION.

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ABSOLUTE MAXIMUM RATINGS AT TA=25°C

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation	150	mW
Reverse Voltage	30	V
Operating Temperature Range	-40°C to + 85°C	
Storage Temperature Range	-55°C to + 100°C	
Lead Soldering Temperature [1.6mm(.063") From Body]	260°C for 5 Seconds	

ELECTRICAL OPTICAL CHARACTERISTICS AT TA=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Reverse Break Down Voltage	V _{(BR)R}	30			V	I _R = 100 μA E _e = 0mW/cm ²
Reverse Dark Current Voltage	I _{D(R)}			30	nA	V _R = 10V E _e = 0mW/cm ²
Open Circuit Voltage	V _{OC}		350		mV	λ = 940nm E _e = 0.5mW/cm ²
Rise Time	T _r		50		nsec	V _R = 10V λ = 940nm R _L = 1KΩ
Fall Time	T _f		50		nsec	
Short Circuit Current	I _S	1.7	2		μA	V _R = 5V λ = 940nm E _e = 0.1mW/cm ²
Total Capacitance	C _T		25		pF	V _R = 3V f = 1MHz E _e = 0mW/cm ²
Wavelength of the Max Sensitivity	λ _{S MAX}		900		nm	

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTICS CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

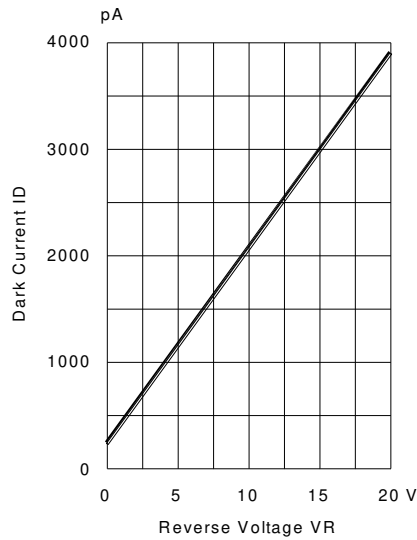


Fig.1 DARK CURRENT VS. REVERSE VOLTAGE
TA=25° C, Ee=0 mW/cm²

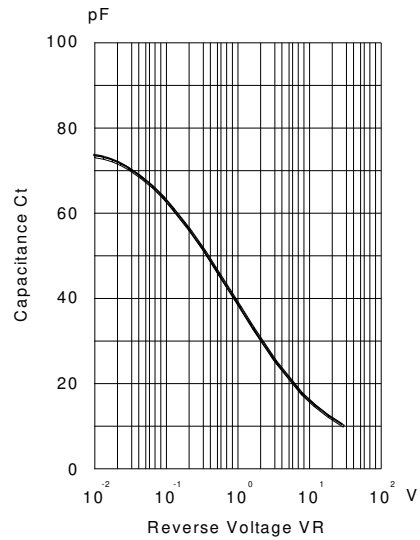


Fig.2 CAPACITANCE VS. REVERSE VOLTAGE
F=1MHZ; Ee=0mW/cm²

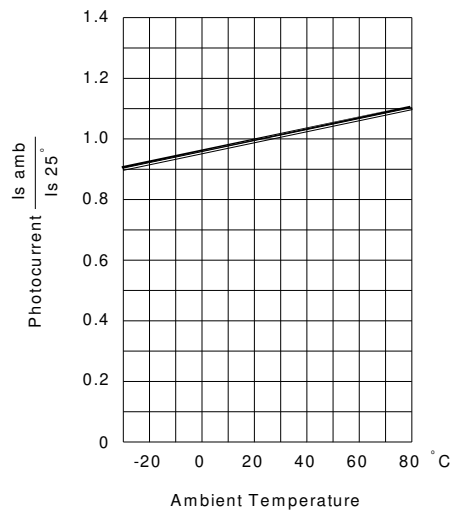


Fig.3 PHOTOCURRENT VS. AMBIENT TEMPERATURE

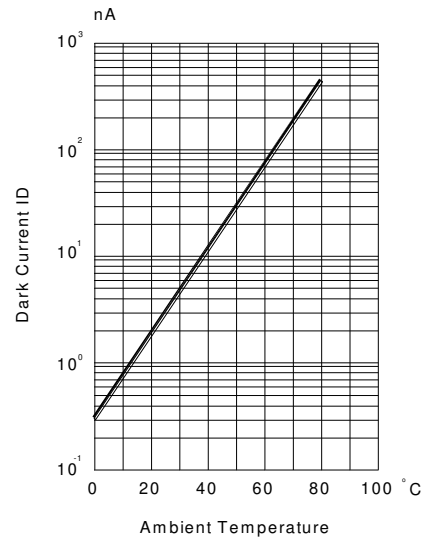


Fig.4 DARK CURRENT AMBIENT TEMPERATURE
VR=10, Ee=0mW/cm²

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTICS CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

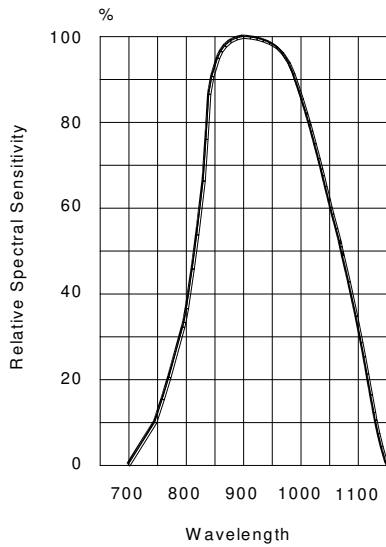


Fig.5 RELATIVE SPECTRAL SENSITIVITY VS WAVELENGTH

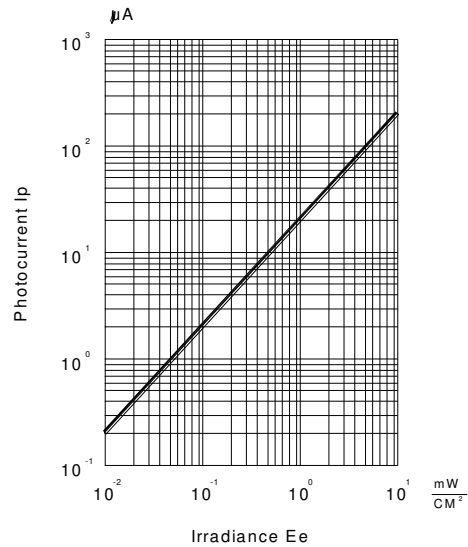


Fig.6 PHOTOCURRENT VS IRRADIANCE $\lambda= 940$ nm

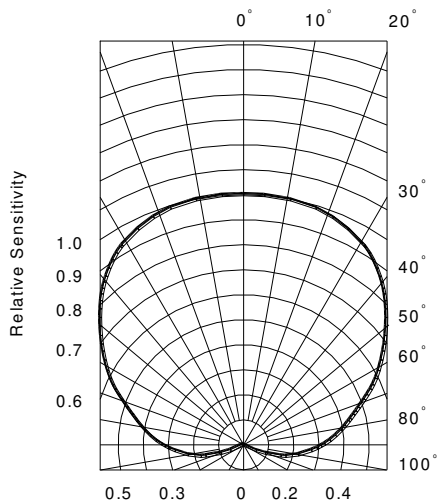


Fig.7 SENSITIVITY DIAGRAM

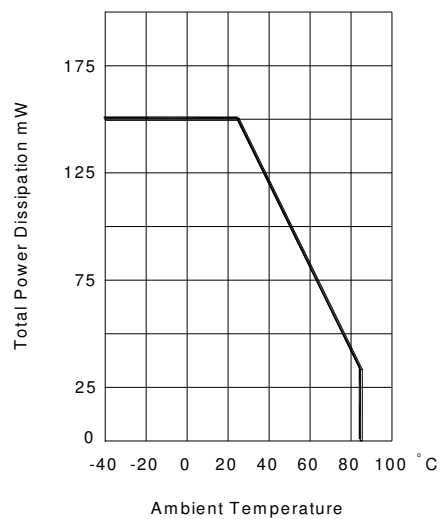


Fig.8 TOTAL POWER DISSIPATION VS AMBIENT TEMPERATURE